



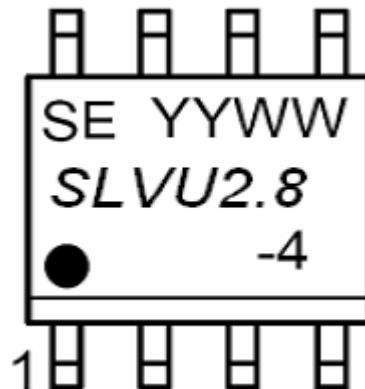
**SHANGHAI SEMITECH SEMICONDUCTOR CO., LTD**

**SLVU2.8-4**

## **SLVU2.8-4 Utralow Capacitance Transient Voltage Suppressors Array**

### **Features**

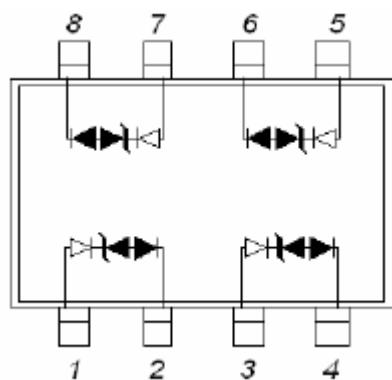
- 400 W Peak Pulse Power per Line ( $t_p=8/20\mu s$ )
- Protects two line pairs(four lines).
- Low capacitance
- Low Leakage Current.
- Low Operating and Clamping Voltages.
- Transient Protection for High Speed Data Lines to  
IEC61000-4-2(ESD) $\pm 15kV$ (air), $\pm 8kV$ (Contact)  
IEC61000-4-4(EFT) 40A(5/50ns)  
IEC61000-4-5(lightning) 24A(8/20us)



**SOP-8**

### **General Description**

The SLVU2.8-4 is in an SOP-8 package and may be used to protect two high-speed line pairs. The “flow-thru” design minimizes trace inductance and reduces voltage overshoot associated with ESD events. The low clamping voltage of the SLVU2.8-4 minimizes the stress on the protected IC.

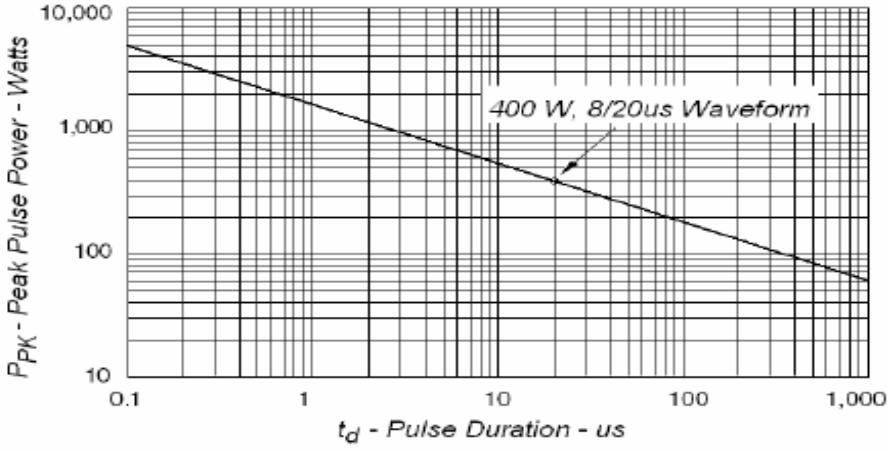


### **Applications**

- Ethernet – 10/100/1000 Base T
  - WAN/LAN Equipment
- Desktops, Servers, Notebooks & Handhelds, base stations Laser Diode Protection

## Absolute Maximum Ratings

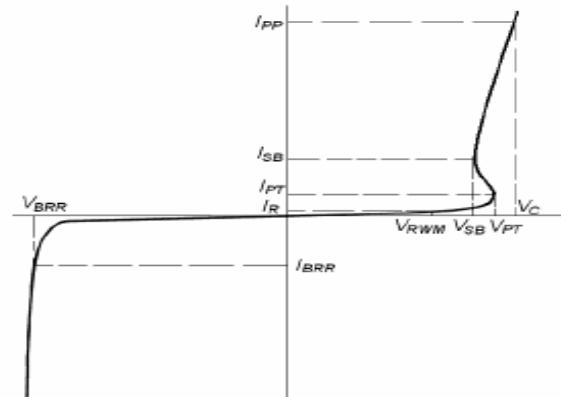
Parameter	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ ) - See Fig1.	$P_{PK}$	400	W
Peak Pulse Current ( $t_p = 8/20\mu s$ )	$I_{PP}$	20	A
Storage Temperature Range	$T_{STG}$	-55 to 150	°C
Operating Junction Temperature Range	$T_J$	-55 to 150	°C


  
 P<sub>PK</sub> - Peak Pulse Power - Watts

**Fig1. Peak Pulse Power VS Pulse Time**

## Electrical Parameter

Symbol	Parameter
$I_{PP}$	Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Reverse Stand-Off Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{SB}$	Snap-Back Voltage @ $I_{SB}$
$I_{SB}$	Snap-Back Current
$V_{PT}$	Punch-Through Voltage
$I_{PT}$	Punch-Through Current
$V_{BRR}$	Reverse Breakdown Voltage @ $I_{BRR}$
$I_{BRR}$	Reverse Breakdown Current



**Fig2.**

## Electrical Characteristics

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$				2.8	V
Punch-Through Voltage	$V_{PT}$	$I_{PT} = 2\mu A$	2.8			V
Snap-Back Voltage	$V_{SB}$	$I_{SB} = 50mA$	2.8			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 2.8V, T=25^\circ C$ (Each Line)			1	uA
Clamping Voltage	$V_C$	$I_{PP} = 2A, t_p = 8/20\mu s$ (Each Line)			5.5	V
Clamping Voltage	$V_C$	$I_{PP} = 5A, t_p = 8/20\mu s$ (Each Line)			8.5	V
Clamping Voltage	$V_C$	$I_{PP} = 24A, t_p = 8/20\mu s$ (Each Line)			15	V
Junction Capacitance	$C_J$	$V_R = 0V, f = 1MHz$ (Each Line)		3.5	5	pF

## Typical Characteristics

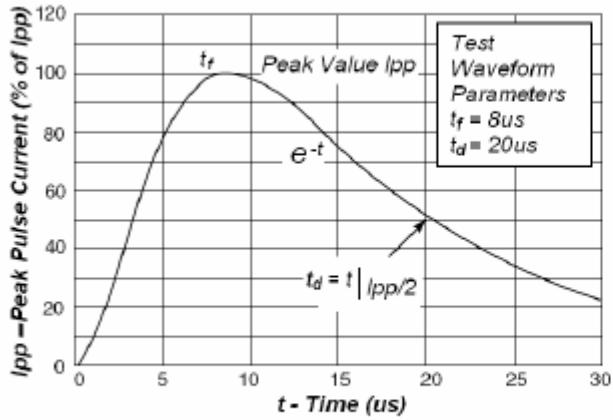


Fig3. Pulse Waveform

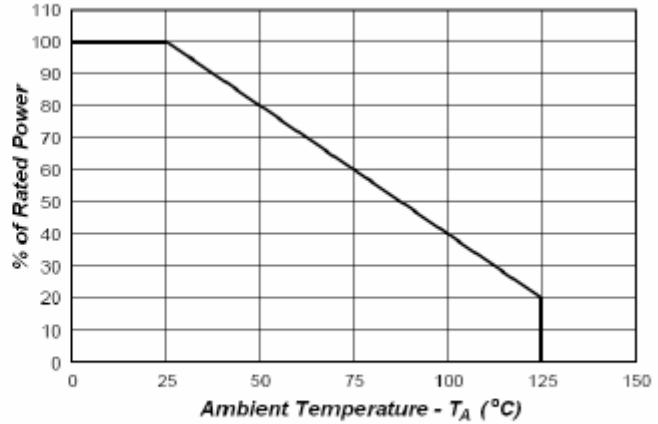


Fig4. Power Derating Curve

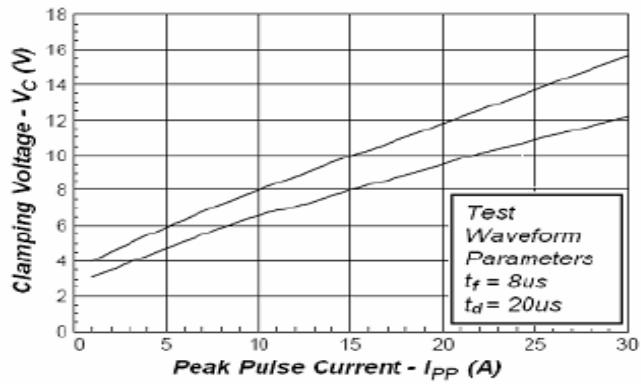


Fig5. Clamping Voltage vs.  
Peak Pulse Current

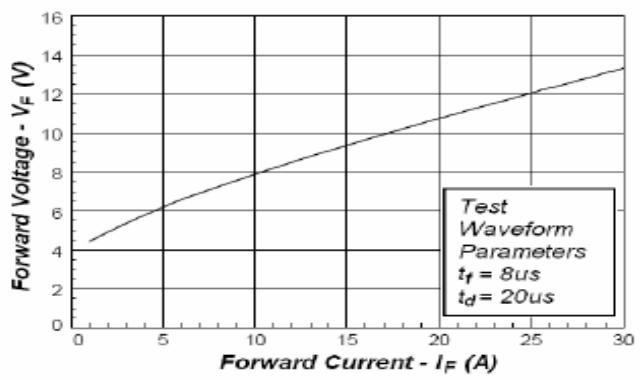


Fig6. Forward Voltage vs.  
Forward Current

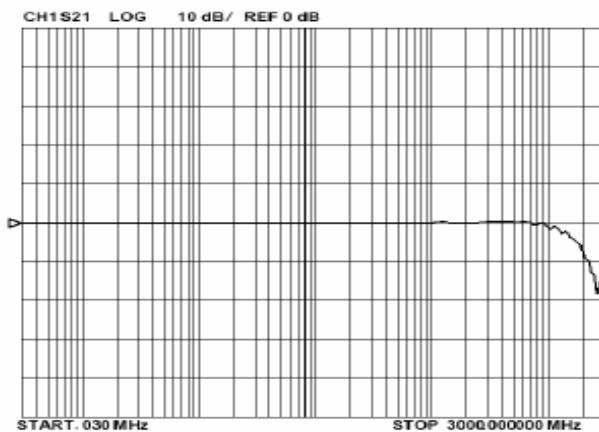


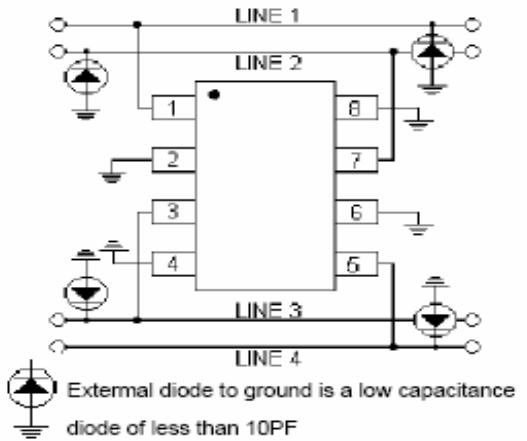
Fig7. Insertion Loss S21

### **Unidirectional Common-Mode Protection (Figure 9)**

The SLVU2.8-4 provides up to four lines of protection in a common-mode configuration as depicted in figure 9.

Circuit connectivity is as follows:

- Line 1 is connected to Pin 1
- Line 2 is connected to Pin 7
- Line 3 is connected to Pin 3
- Line 4 is connected to Pin 5
- Pins 2, 4, 7 and 8 are connected to ground



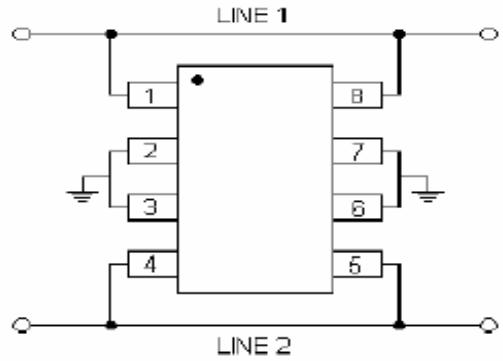
**Fig9.**

### **Bidirectional Common-Mode Protection (Figure 10)**

The SLVU2.8-4 provides up to two lines of protection in a common-mode configuration as depicted in figure 10.

Circuit connectivity is as follows:

- Line 1 is connected to Pins 1 & 8
- Line 2 is connected to Pins 4 & 5
- Pins 2, 3, 6, and 7 are connected to ground



**Fig10.**

### **Bidirectional different-Mode Protection (Figure 11)**

The SLVU2.8-4 provides up to two-line pairs of protection in a differential-mode configuration as depicted in figure 11.

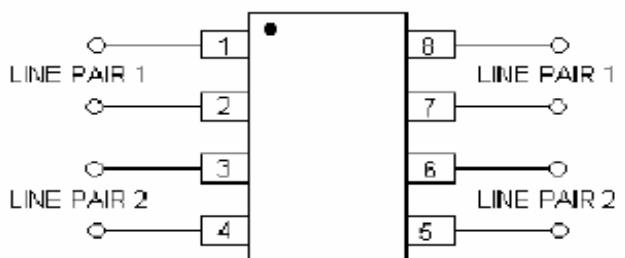
Circuit connectivity is as follows:

- Line Pair 1 is connected to Pins 1 & 2
- Line Pair 1 is connected to Pins 7 & 8
- Line Pair 2 is connected to Pins 3 & 4
- Line Pair 2 is connected to Pins 5 & 6

### **Circuit Board Layout Protection**

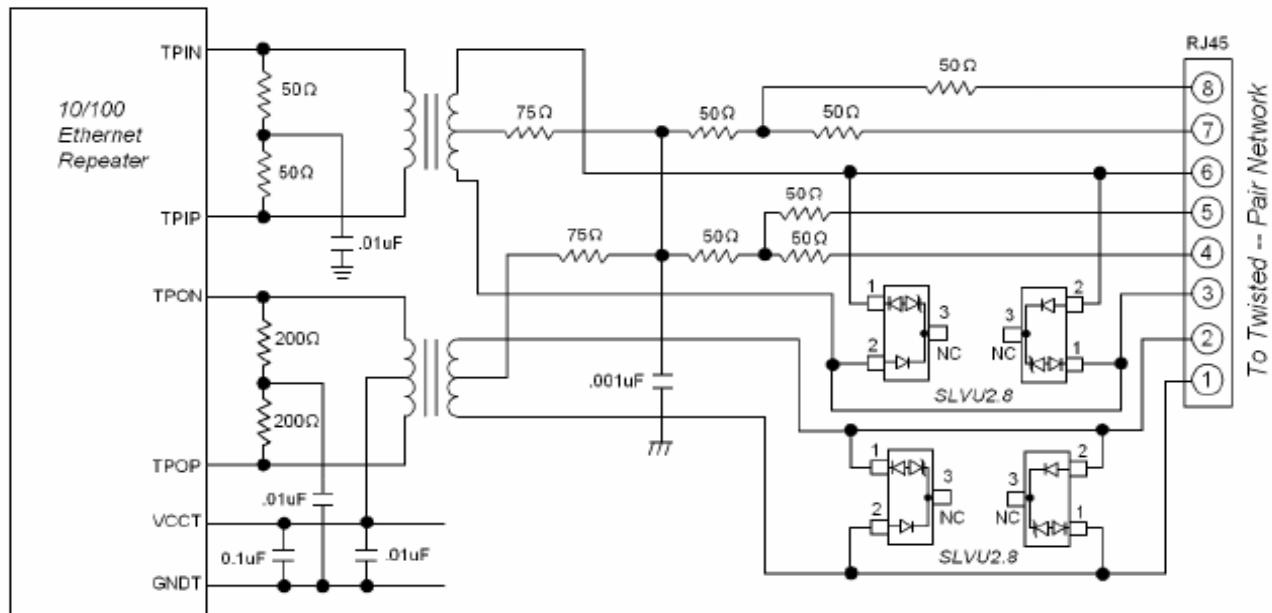
Circuit board layout is critical for Electromagnetic Compatibility (EMC) protection. The following guidelines are recommended:

- The protection device should be placed near the input terminals or connectors, the device will divert the transient current immediately before it can be coupled into the nearby traces.
- The path length between the TVS device and the protected line should be minimized.
- All conductive loops including power and ground loops should be minimized.
- The transient current return path to ground should be kept as short as possible to reduce parasitic inductance.
- Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

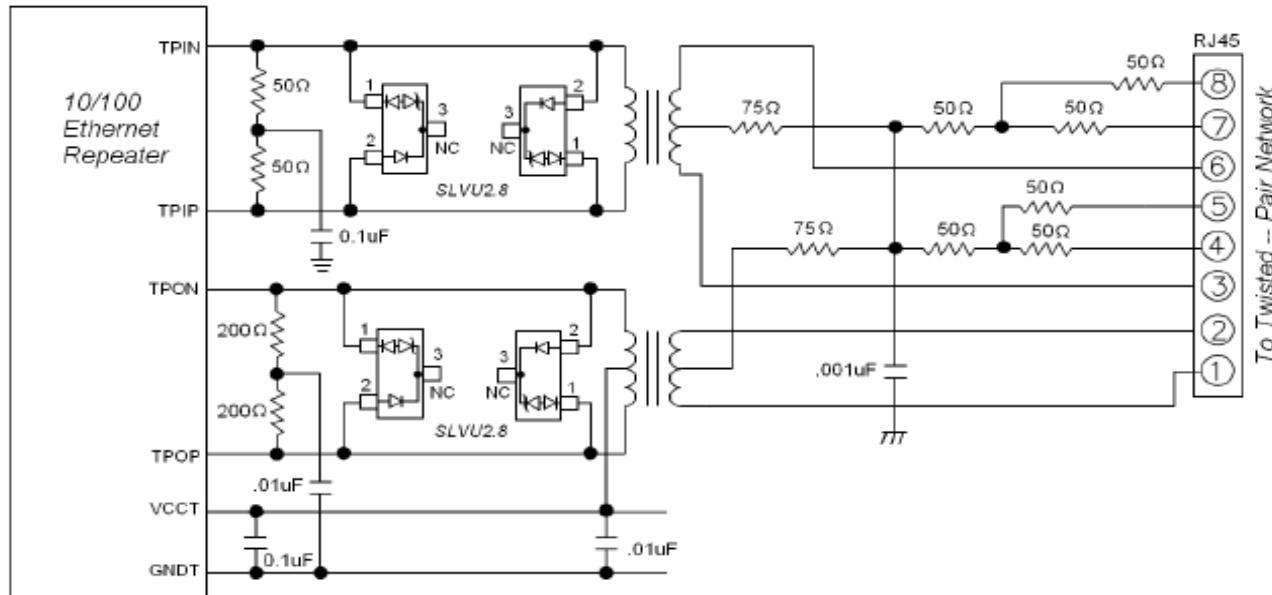


**Fig11.**

## Typical Applications



**Fig12. 10/100 Ethernet Protection Circuit**



**Fig13. 10/100 Ethernet "Enhanced" Lightning Protection Circuit**

**SOT-23 MECHANICAL DATA**

Dim	Millimeters		
	Min	TYP	Max
<b>A</b>	1.00		1.40
<b>A1</b>	0		0.10
<b>A2</b>	1.00		1.30
<b>b</b>	0.35		0.50
<b>c</b>	0.10		0.20
<b>D</b>	2.70	2.90	3.10
<b>E</b>	2.40		2.80
<b>E1</b>	1.40		1.60
<b>e</b>	0.85		1.15
<b>e1</b>		1.90	
<b>L1</b>	0.40	.	
<b>q</b>	0°		10°
<b>s</b>	0.45		0.55

